



USSP8021

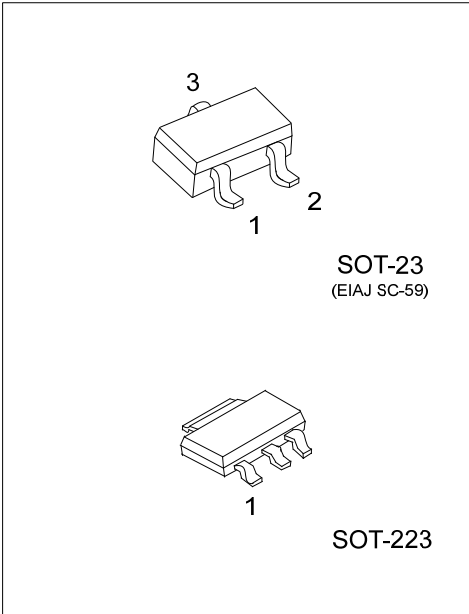
Preliminary

PNP EPITAXIAL SILICON TRANSISTOR

-21V, -8.0A PNP LOW $V_{CE(SAT)}$ TRANSISTOR

■ **FEATURES**

- * Low collector-emitter saturation voltage $V_{CE(SAT)}$
- * High collector current capability: I_C and I_{CM}
- * Higher efficiency leading to less heat generation
- * Reduced printed-circuit board requirements
- * Complement: USSN8021



■ **ORDERING INFORMATION**

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
USSP8021L-AA3-R	USSP8021G-AA3-R	SOT-223	B	C	E	Tape Reel
USSP8021L-AE3-R	USSP8021G-AE3-R	SOT-23	B	E	C	Tape Reel

Note: Pin Assignment: B: Base C: Collector E: Emitter

<p>USSP8021G-AA3-R</p>	<p>(1) R: Tape Reel</p> <p>(2) AA3: SOT-223, AE3: SOT-23</p> <p>(3) G: Halogen Free and Lead Free, L: Lead Free</p>
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■ **MARKING**

SOT-223	SOT-23

■ ABSOLUTE MAXIMUM RATING (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V _{CB0}	-21	V
Collector-Emitter Voltage		V _{CEO}	-21	V
Emitter-Base Voltage		V _{EBO}	-5	V
Collector Current	DC	I _C	-8	A
	Peak	I _{CM}	-16	A
Power Dissipation (T _A ≤ 25°C)	SOT-223	P _D	1	W
	SOT-23		0.35	W
Junction Temperature		T _J	+150	°C
Storage Temperature		T _{STG}	-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Device mounted on a FR4 printed-circuit board, single-sided copper; tin-plated, mounting pad for collector 1 cm².

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	θ _{JA}	125	°C/W
	SOT-23		357	°C/W
Junction to Case	SOT-223	θ _{JC}	10	°C/W
	SOT-23		90	°C/W

Note: Device mounted on a FR4 printed-circuit board, single-sided copper; tin-plated, mounting pad for collector 1 cm².

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector to Base Breakdown Voltage	BV _{CB0}	I _C =-100μA, I _E =0	-21			V
Collector to Emitter Breakdown Voltage	BV _{CEO}	I _C =-1mA, I _B =0	-21			V
Emitter to Base Breakdown Voltage	BV _{EBO}	I _E =-100μA, I _C =0	-8			V
Collector Cut-Off Current	I _{CBO}	V _{CB} =-20V, I _E =0			-100	nA
		V _{CB} =-20V, I _E =0, T _J =150°C			-50	μA
Collector Cut-Off Current	I _{CES}	V _{CE} =-10V, V _{BE} =0			-100	nA
Emitter Cut-Off Current	I _{EBO}	V _{EB} =-5V, I _C =0			-100	nA
Collector-Emitter Saturation Voltage (Note)	V _{CE(SAT)}	I _C =-1A, I _B =-50mA			-60	mV
		I _C =-1A, I _B =-10mA			-120	mV
		I _C =-2A, I _B =-40mA			-150	mV
		I _C =-4A, I _B =-200mA			-220	mV
		I _C =-7A, I _B =-350mA			-350	mV
		I _C =-8A, I _B =-800mA			-600	mV
Base-Emitter Saturation Voltage (Note)	V _{BE(SAT)}	I _C =-1A, I _B =-400mA			-0.9	V
		I _C =-6A, I _B =-600mA			-1.2	V
		I _C =-8A, I _B =-800mA			-1.3	V
Base-Emitter Turn-On Voltage (Note)	V _{BE(ON)}	V _{CE} =-2V, I _C =-2A			-1	V
Dc Current Gain (Note)	h _{FE}	V _{CE} =-2V, I _C =-500mA	230			
		V _{CE} =-2V, I _C =-1.0A	300			
		V _{CE} =-2V, I _C =-2.0A	300			
		V _{CE} =-2V, I _C =-4.0A	250			
		V _{CE} =-2V, I _C =-6.0A	230			
		V _{CE} =-2V, I _C =-8.0A	200			
Transition Frequency	f _T	I _C =-100mA, V _{CE} =-10V, f=100MHz	50			MHz

Note: Pulse test: t_p ≤ 300μs, Duty cycle ≤ 2%.

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